

Monodisperse Formamidinium Lead Bromide Nanocrystals with Bright and Stable Green Photoluminescence

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Supporting Information

ABSTRACT: Bright green emitters with adjustable photoluminescence (PL) maxima in the range of 530–535 nm and full-width at half-maxima (fwhm) of <25 nm are particularly desirable for applications in television displays and related technologies. Toward this goal, we have developed a facile synthesis of highly monodisperse, cubic-shaped formamidinium lead bromide nanocrystals (FAPbBr₃ NCs) with perovskite crystal structure, tunable PL in the range of 470–540 nm by adjusting the nanocrystal size (5–12 nm), high quantum yield (QY) of up to 85% and PL fwhm of <22 nm. High QYs are also retained in films of FAPbBr₃ NCs. In addition, these films exhibit low thresholds of $14 \pm 2 \mu\text{J cm}^{-2}$ for amplified spontaneous emission.

In the last several years, lead halide semiconductors with perovskite crystal structures have emerged as very popular optoelectronic materials, initially in the context of highly efficient photovoltaics with power conversion efficiencies exceeding 22%¹ and as versatile photonic sources. In particular, nanocrystals (NCs) of colloidal cesium lead halides (CsPbX₃, X = Cl, Br, or I, or a mixture thereof) have been recently shown to possess outstanding optical properties such as broadly tunable photoluminescence (PL) (410–700 nm), small full-width at half-maxima (fwhm = 12–40 nm for blue to red) and high PL quantum yields (QYs = 50–90%).² At present, these materials are undergoing further chemical engineering³ and are intensely investigated in several respects, e.g., as to their surface chemistry,⁴ lasing characteristics⁵ and service in light-emitting devices.^{4b,6} In the near future, the technologically most feasible application of these NCs is in television displays and related devices, where perovskite NCs might act as green and red emitters excited by standard blue-emitting diodes. Bright-green PL with adjustable maxima in the range of 530–535 nm, a facile reproducibility of $\pm 1\%$ or better, and fwhm of <25 nm is a particularly desirable milestone, considering NTSC and more recent Rec.2020 color standards. Our studies on CsPbX₃ NCs have demonstrated the difficulties in achieving and maintaining such desirable “530–535 nm” PL in a solid, polymer-embedded

state. First of all, both the PL peak and absorption edge from CsPbBr₃ NCs do not exceed 520 nm, even at NC sizes far beyond the quantum-confinement regime (>10 nm). This is indicative of the fact that the “apparent bulk bandgap” of CsPbBr₃ NCs is higher than that obtained with large single crystals (with a band gap of 2.25 eV at, e.g., 551 nm).⁷ At present, the atomistic origin of this difference is unclear. The broad X-ray diffraction (XRD) reflections of CsPbBr₃ NCs make it difficult to differentiate between the orthorhombic (nearly cubic) lattice of the bulk material and other possible distortions of the ideal cubic lattice. The PL maxima can be pushed to the desired 530–535 nm wavelengths compositionally, by forming CsPbBr_{3-x}I_x (x \approx 0.3). However, this shift is accompanied by a drop of QY from 90 to $\leq 50\%$. Furthermore, CsPbBr_{3-x}I_x NCs exhibit low chemical stability in the solid-state, presumably due to phase-separation into CsPbBr₃ and CsPbI₃. Considerable attention has also been devoted to hybrid perovskites, methylammonium lead halides (MAPbX₃), in the form of colloidal NCs.⁸ A particular challenge facing MA-based compounds is their chemical decomposition, releasing gaseous methylamine.

In this work, we explored a closely related compound FAPbBr₃, where FA⁺ stands for CH(NH₂)₂⁺ (formamidinium). We present a colloidal synthesis of FAPbBr₃ NCs and strong evidence that these NCs may overcome the difficulties facing CsPbBr₃ NCs in achieving bright and stable emission at 530–535 nm. In a typical hot-injection synthesis (method 1, see Supporting Information for further details), FA-Pb precursor solution was prepared by reacting Pb and FA acetates (0.2 and 0.75 mmol, respectively) with oleic acid (OA, 2 mL) in octadecene (ODE, 8 mL). At 130 °C, oleylammonium bromide (OAmBr, 0.6 mmol, dissolved in 2 mL of toluene) was injected. After 10 s, the FAPbBr₃ NCs were cooled to room temperature and purified using toluene and acetonitrile as a solvent and nonsolvent, respectively. This simple synthesis yields brightly luminescent, cubic-shaped and highly monodisperse FAPbBr₃ NCs (Figure 1), with standard size deviation below 5% (Figure S1).

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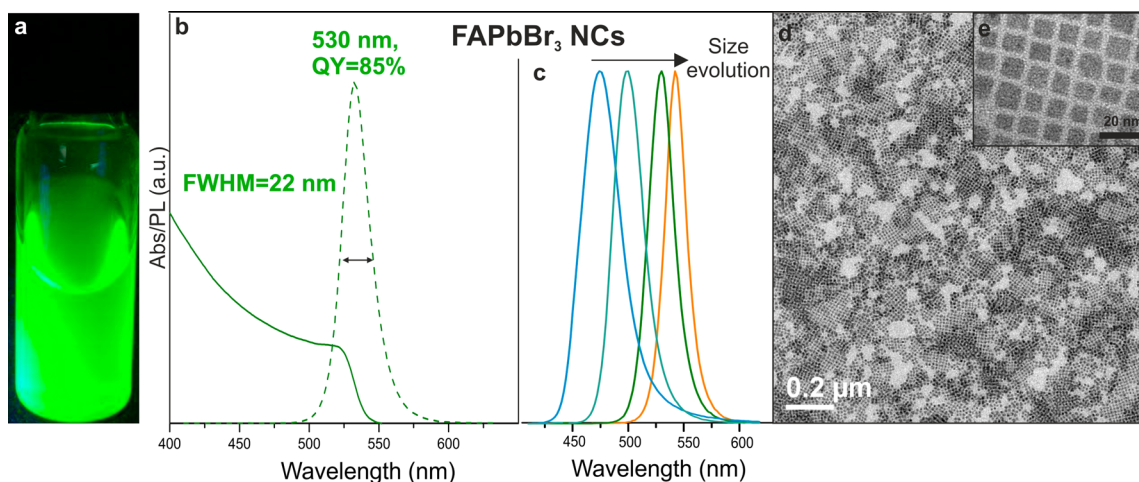


Figure 1. (a) Photograph of colloidal FAPbBr₃ NCs in toluene solution under a UV lamp ($\lambda = 365$ nm), (b) absorption and PL spectra of ~ 12 nm FAPbBr₃ NCs with a PL maximum at 530 nm, fwhm of 22 nm and QY of 85%, (c) PL spectra for FAPbBr₃ NCs showing the red shift of the emission peak with increasing size from 5 to >50 nm, (d,e) TEM images of ~ 12 nm FAPbBr₃ NCs.

The excellent PL properties of FAPbBr₃ NCs are exemplified by those of 12 nm in size, which exhibit a PL maximum at 530 nm, QY of 85% and fwhm of 22 nm (Figure 1b). The PL can be tuned in a wide range from 470 to 535 nm via size effects alone, without altering the composition. With NC sizes of up to 50 nm (Figure S2), PL peak values of up to 550 nm can be achieved, similar to the range reported for thin-film and bulk FAPbBr₃ (550–575 nm).⁹ Size-engineering was accomplished by adjusting either the amount of OAmBr injected (a higher quantity leads to smaller NCs, Figure S3) or the reaction temperature (between 70 and 165 °C, higher yielding larger size). We note that this synthesis (method 1) is significantly different from our previous work on CsPbBr₃ NCs, where PbBr₂ (dissolved in oleylamine, OLA, and OA) was used as a Pb–Br dual-source precursor.² Such a CsPbBr₃-like synthesis of FAPbBr₃ NCs (method 2, see Supporting Information for details), which is by injection of FA-oleate precursor into PbBr₂/oleylamine/oleic acid mixture, yields a much broader size distribution of the NCs (Figure S4) than method 1. We attribute this to the detrimental role of molecular OLA, presumably causing deprotonation of FA⁺. Likewise, no FAPbBr₃ NCs could be obtained also when neutral OLA is introduced into method 1. An alternative Br-precursor, CH₃MgBr, has also been tested (method 3, see Supporting Information for details), leading to even faster reaction kinetics and thus poorer control over the NC size (Figure S5) than with OAmBr precursor. The complete absence of OLA or OAm⁺ led to lower colloidal stability, reinforcing the OAmBr-based method 1 as, thus far, the optimal synthesis route. Besides acting as the Br source, OAmBr also brings the OAm⁺ cation that together with the oleate-anion acts as capping ligands at the NC surfaces, presumably similarly to the CsPbBr₃ system.^{4a} Oleylammonium oleate is the sole byproduct of the synthesis (method 1) and a capping ligand at the same time, with oleate coordinating surface cations and OAm⁺ binding to surface anions. It is essential that the FA:Pb molar ratio is maintained above 2 in order to obtain stable luminescence materials. For FA:Pb ratios lower than 2, the obtained NCs rapidly decomposed. In contrast, CsPbBr₃ NCs require a high excess of Pb for optimal growth.^{2,3g}

XRD studies on FAPbBr₃ NCs in thin films (Figure S6, laboratory data) and in solutions (Figure 2, synchrotron data)

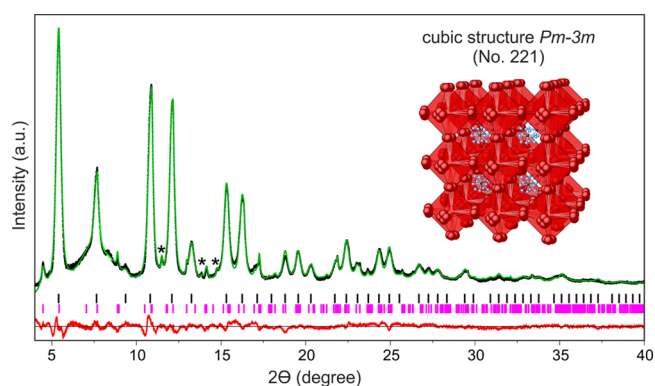


Figure 2. Synchrotron XRD pattern ($\lambda = 0.565\ 666$ Å) and its Rietveld fit for ~ 12 nm FAPbBr₃ NCs, containing an impurity of NH₄Pb₂Br₅ (~ 6 wt %). Black, experimental data; green, calculated total trace that combines *Pm* $\bar{3}m$ model of FAPbBr₃ and the *I4/mcm* model of NH₄Pb₂Br₅;¹⁰ red, difference plot; black and magenta vertical bars indicate Bragg peak locations for FAPbBr₃ and NH₄Pb₂Br₅, respectively. Stars highlight minor peaks of an unknown contaminant. The inset illustrates the crystal structure of FAPbBr₃ and disorder of Br-anions.

indicated the same primitive cubic structure (space group *Pm* $\bar{3}m$, no. 221) reported for bulk crystals, with a small, but measurable, increase of the unit cell parameter with respect to bulk (6.002 vs 5.992 Å).¹¹ In FAPbBr₃, the PbBr₆ octahedra share their corners and the Br anions are disordered in four equivalent positions; consequently, the Pb–Br–Pb and *cis*-Br–Pb–Br bond angles appear to deviate from their ideal values of 180° and 90°, respectively, by up to 15°. As the slight reorientation of the PbBr₆ octahedra is likely to occur as rigid-body rotations, of the 24 disordered Br ions surrounding a central Pb atoms, only 6 coherently define a regular octahedron, with *cis*-Br–Pb–Br angles of 90°. This finding implies a severe conditioning of the connectivity pattern of the neighboring octahedra, which cannot be considered cubic at the very local scale, but only on average. With the aim of explaining the chemical reason for such a deviation from linearity, it has been recently proposed that the tilting of the PbBr₆ octahedra leads to a higher degree of space filling and, therefore, to a larger stability of the crystal structure.¹¹ A careful analysis of the

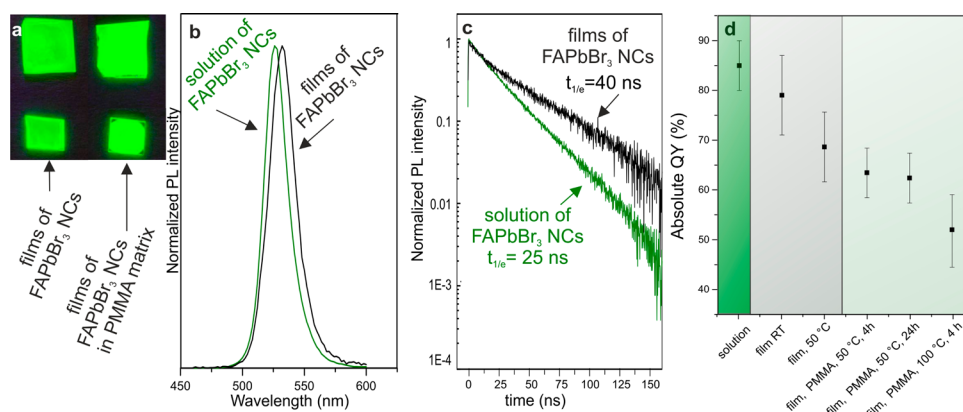


Figure 3. (a) Photograph of highly luminescent FAPbBr₃ NC films (bare and embedded in PMMA), under a UV lamp ($\lambda = 365$ nm). (b) PL spectra of ~ 12 nm FAPbBr₃ NCs in colloidal solution and in films. (c) Time-resolved (TR) PL traces for a solution and films of FAPbBr₃ NCs. (d) PL QYs of FAPbBr₃ NCs in various states: solution, bare films and polymer- (PMMA-) encapsulated films. All samples were prepared and tested in air.

synchrotron XRD pattern from the as-synthesized colloid detected a nanocrystalline impurity of NH₄Pb₂Br₅,¹⁰ amounting typically to 5–10%. NH₄⁺ could form by thermal decomposition of FA⁺ during the synthesis of NCs.¹²

On the basis of our experience with CsPbBr₃ and MAPbBr₃ NCs,^{2,8c} the only alternatives within the APbBr₃ family, we find FAPbBr₃ to be much more robust in several regards. When an identical, repetitive precipitation/redispersion procedure (with acetonitrile/toluene) is applied to any of the APbBr₃ NCs, only FAPbBr₃ can retain bright PL after 2–3 cycles of purification. CsPbBr₃ NCs assume a nonluminescent state, whereas MAPbBr₃ NCs quickly decomposed. The PL properties and stability of purified FAPbBr₃ NCs were then investigated in films (Figure 3). A small, 5–10 nm shift in the PL peak is systematically seen upon preparation as films, compared to the solution spectra. The time-resolved (TR) PL traces from solutions of 12 nm NCs (Figure 3c) and from smaller NCs (8 nm, Figure S7) are monoexponential with lifetimes of 25 and 7 ns, respectively. Such a size effect can be attributed to the higher exciton binding energy in such small crystallites due to quantum confinement. The QYs for both NC sizes were >70%. Contrary to conventional quantum dots, such as CdSe and InP NCs, perovskite NCs feature unusual, defect-tolerant photophysics,¹³ i.e., surface dangling bonds and intrinsic point defects such as vacancies do not form a high density of midgap states, known to trap carriers and thereby quench PL. CdSe and InP NCs, being defect-intolerant, require epitaxial passivation layers in order to exhibit bright PL. TR-PL traces from films of 12 nm FAPbBr₃ NCs show two characteristic lifetimes: one similar to the corresponding colloidal solution and a second, longer component (40 ns) that can be attributed to increased exciton delocalization. The longer-living component has not been observed in the closely related CsPbBr₃ NC system.² FAPbBr₃ NC films that were dried at room temperature exhibited QYs up to 81%, whereas films dried at 50 °C for 24 h in air exhibited reduced QYs of 70%. The ability of FAPbBr₃ NCs to retain bright PL also in the polymer-embedded form and under mild heating at 50–60 °C was then investigated. Such luminescent polymer films might eventually be used as backlight films in television displays.

NCs were mixed with poly(methyl methacrylate) (PMMA) in toluene, followed by drying at 50 °C for 4 h in air. These as-prepared films exhibited QYs of $\sim 65\%$, without noticeable deterioration after 24 h. Higher temperature annealing (at 100

°C, 4 h) still resulted in high QYs of $\sim 50\%$. Identical experiments with CsPbBr₃ NCs led to QYs not exceeding 10% (Figure S8). Long-term-stability of FAPbBr₃ NC films requires additional investigations and further improvements are expected through various encapsulation strategies (core–shell morphologies, embedding into crystalline matrix, etc.).

High PL QYs and exciton delocalization may assist in achieving lasing from FAPbBr₃ NC emitters.^{5a} Figure 4

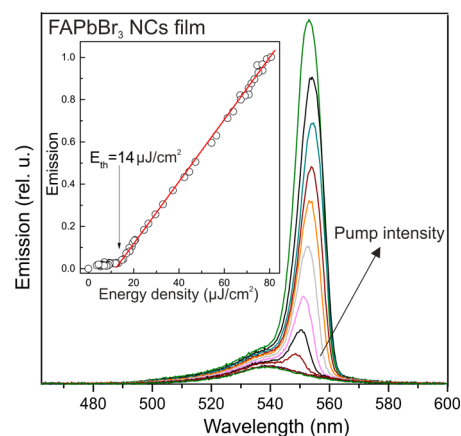


Figure 4. Amplified spontaneous emission (ASE) from a film of ~ 12 nm FAPbBr₃ NCs. Inset: threshold behavior for the intensity of the ASE band.

presents amplified spontaneous emission (ASE) spectra of a film comprising ~ 12 nm FAPbBr₃ NCs, obtained upon pulsed excitation (400 nm, 100 fs). The initial PL peak with a fwhm of 26 nm is red-shifted by 14 nm and exhibits much narrower emission line widths (fwhm = 9 nm), a clear signature of ASE. The redshift of the ASE band can be explained by the biexcitonic nature of the optical gain.¹⁴ The pump intensity threshold for ASE is $14 \pm 2 \mu\text{J cm}^{-2}$, one of the lowest among colloidal NCs emitting in the green range.^{5a,14a,15}

In conclusion, we have presented a colloidal synthesis of highly uniform FAPbBr₃ NCs. These NCs retain their bright emission with QYs of 50–80% in thin films and in a polymer-embedded state, paving the way to a variety of applications such as blue-to-green down-converters or color enhancers in television displays, and in light-emitting diodes.

■ ASSOCIATED CONTENT**■ Supporting Information**

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/jacs.6b08900.

Experimental methods and supplementary figures (PDF)

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Notes

The authors declare no competing financial interest.

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